# Mr Wang 13602525365

### **Analog Power**

#### AM6924NHE

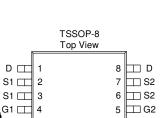
#### **Dual N-Channel Logical Level MOSFET**

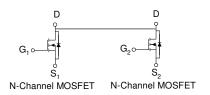
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These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)}$ (OHM)	$I_{D}(A)$		
20	$0.013 @ V_{GS} = 4.5 V$	7.9		
	$0.018 @ V_{GS} = 2.5V$	6.7		

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSSOP-8 saves board space
- Fast switching speed
- High performance trench technology ESD





#### Protected

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			20	V	
Gate-Source Voltage		$V_{GS}$	±8	<b>v</b>	
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	.T_	7.9	. 7	
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ър	6.5	A	
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	±30			
Continuous Source Current (Diode Conduction) <sup>a</sup>			1.5	Α	
$T_A=25^{\circ}C$		D_	1.2	$\mathbf{w}$	
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	I D	0.8		
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typ	Max	
M · I · · a	t <= 10 sec	D	72	83	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	$R_{thJA}$	100	120	C/W

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#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static	•			~ ~	•	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{GS} = V_{DS}$ , $I_D = 250 \text{ uA}$	0.3			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			±10	μΑ
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
Zero Gate Voltage Drain Current	<sup>1</sup> DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	μΑ
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			A
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_{D} = 1 \text{ A}$			0.013	Ω
Drain-Source On-Resistance	*DS(on)	$V_{GS} = 2.5 \text{ V}, I_{D} = 1 \text{ A}$			0.018	
Forward Tranconductance <sup>A</sup>	$g_{\mathrm{fs}}$	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ A}$		25		S
Diode Forward Voltage <sup>A</sup>	$V_{SD}$	$I_S = 1 A, V_{GS} = 0 V$		0.7		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_{g}$			10		
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =10V, $V_{GS}$ =4.5V, $I_{D}$ =1A		1		nC
Gate-Drain Charge	$Q_{\mathrm{gd}}$			3		]
Turn-On Delay Time	t <sub>d(on)</sub>			10		nS
Rise Time	t <sub>r</sub>	$V_{DD}$ =10V, $V_{GS}$ =4.5V, $I_{D}$ =1A , $R_{GEN}$ =10 $\Omega$		10		
Turn-Off Delay Time	$t_{d(off)}$			80		
Fall-Time	t <sub>f</sub>			20		

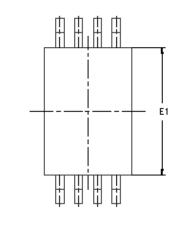
#### Notes

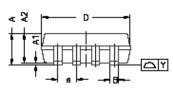
- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

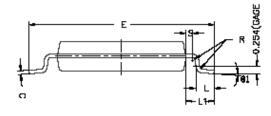
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## Package Information

TSSOP-8: 8LEAD







MILLIMETERS				
MIN.	NDM.	MAX.		
1.05	1.10	1.20		
0.05	0.10	0.15		
0.99	1.02	1.05		
D.19	0.25	0.30		
	0.127			
2.90	3.0D	3.10		
6.20	6.40	6.60		
4.30	4.40	4.50		
0.659SC				
0.45	0.60	0.75		
0.90	1.00	1.10		
		0.10		
<b></b>	4	e <b>t</b>		
D.09				
0.20				
	MIN. 1.05 0.05 0.99 0.19 2.80 6.20 4.30 0.46 0.90 0.09	MIN. NDM. 1.05 1.10 0.05 0.10 0.99 1.02 D.19 0.25 0.127 2.90 3.00 6.20 6.40 4.30 4.40 0.659SC 0.45 0.60 0.90 1.00 D' 4* D.09		